

1A、2.25MHz、同步降压DC-DC转换器

**UM3510S SOT23-6
UM3510DA DFN6 2.0×2.0**

描述

UM3510是高效的脉宽调制(PWM)同步降压DC-DC转换器，输入电压范围为2.5V至6.0V，可为单块锂离子电池提供高达1000mA的输出电流。UM3510在2.25MHz固定开关频率下运行，进入省电模式后可在轻负载条件下保持高效率。

对于低噪声应用，UM3510可通过将MODE引脚的电平拉高来强制芯片进入固定频率脉宽调制(PWM)模式。

当EN引脚拉低时，UM3510进入关断模式，工作电流降至 $1\mu A$ 以下。该器件还具备2%精度的低内部基准电压、过温保护和过流保护等其他特性。

UM3510采用SOT23-6和6引脚DFN 2mm×2mm封装。

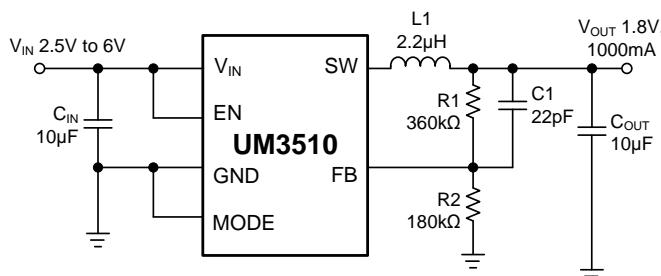
应用

- 蜂窝电话和智能手机
- 微处理器和DSP核心电源
- 无线和DSL解调器
- PDAs、GPS
- WLAN
- 便携式仪器

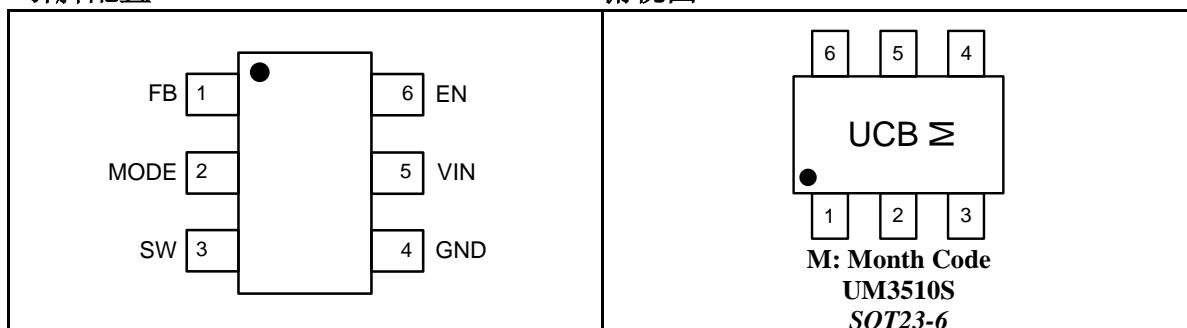
特性

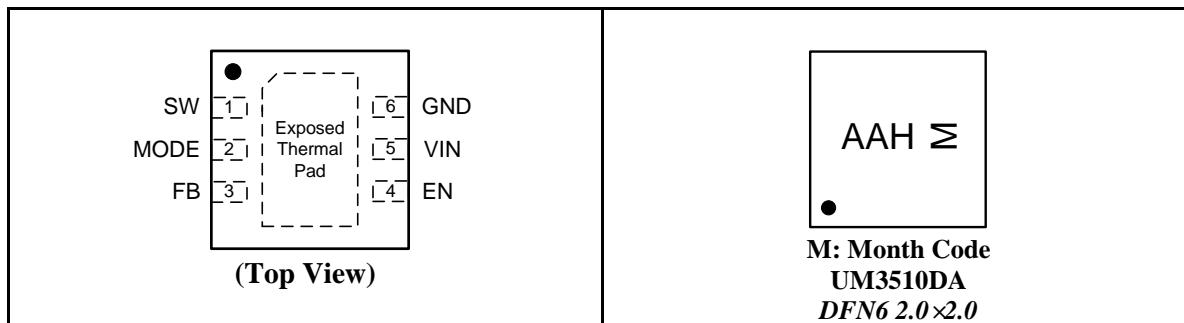
- 效率高达95%
- 恒定开关频率：2.25MHz
- 输出电流：1000mA
- 集成主开关和同步整流器，无需肖特基二极管
- 输入电压范围：2.5V至6.0V
- 低静态电流： $56\mu A$
- 过温保护
- 关断电流： $<1\mu A$

典型应用电路



引脚配置



Pin Configurations
Top View

Ordering Information

| Part Number | Packaging Type | Marking Code | Shipping Qty |
|-------------|----------------|--------------|------------------------------|
| UM3510S | SOT23-6 | UCB | 3000pcs/7Inch Tape & Reel |
| UM3510DA | DFN6 2.0×2.0 | AAH | |

Pin Description

| Pin Number | | Symbol | Function |
|------------|-----------------|--------|---|
| SOT23-6 | DFN6 2.0×2.0 | | |
| 3 | 1 | SW | Power switch output. It is the switch node connection to the inductor. This pin connects to the drains of the internal P-CH and N-CH MOSFET switches. |
| 2 | 2 | MODE | MODE pin=high forces the device to operate in fixed-frequency PWM mode. Mode pin=low enables the Power Save Mode with automatic transition from PFM mode to fixed-frequency PWM mode. |
| 1 | 3 | FB | Feedback input pin. Connect FB to the center point of the external resistor divider. |
| 6 | 4 | EN | Regulator enable control input. Pulling this pin to high enables the device. Pulling this pin to low forces the device into shutdown mode. This pin must be terminated. |
| 5 | 5 | VIN | Input voltage. |
| 4 | 6 | GND | Ground. |

Absolute Maximum Ratings (Note 1)

| Symbol | Parameter | Value | Unit |
|-----------------------------------|---------------------------------|------------------------------|------|
| V _{IN} | Input Voltage | -0.3 to +6.0 | V |
| V _{EN} , V _{FB} | EN, FB Voltages | -0.3 to V _{IN} +0.3 | V |
| V _{SW} | SW Voltage | -0.3 to V _{IN} +0.3 | V |
| I _{SW} | Peak SW Sink and Source Current | 2.0 | A |
| T _O | Operating Temperature | -40 to +85 | °C |
| T _{STG} | Storage Temperature Range | -65 to +150 | °C |

Note 1: Stresses greater than those listed under Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Thermal Capabilities

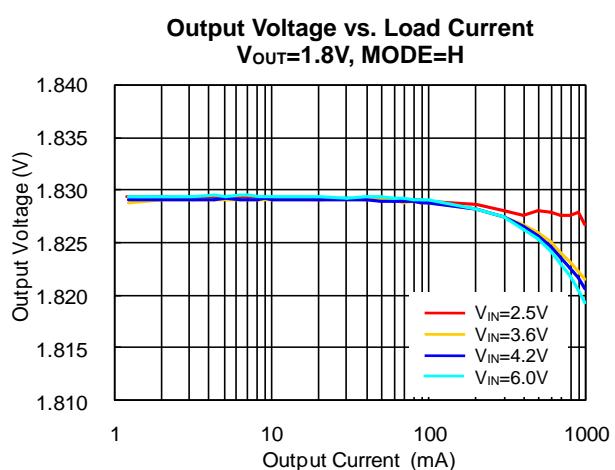
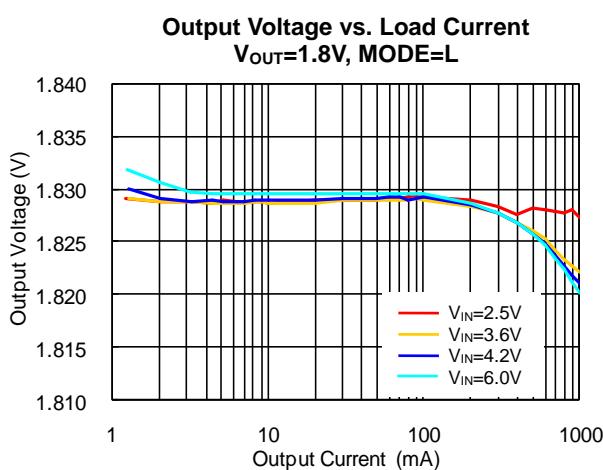
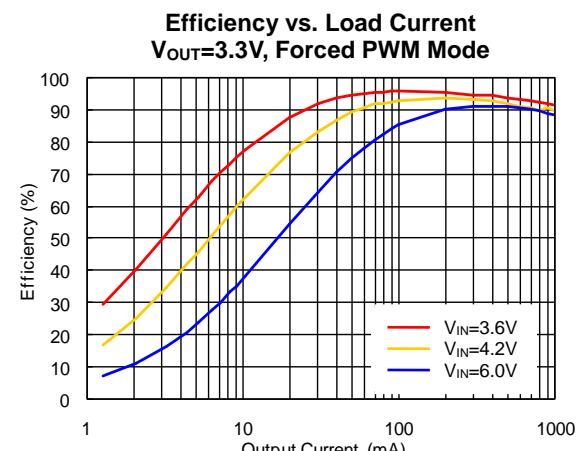
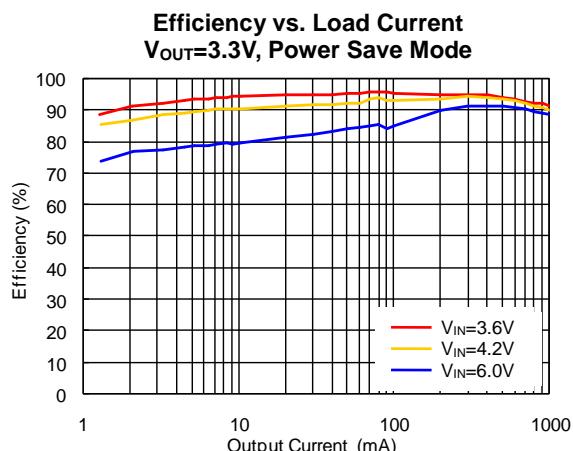
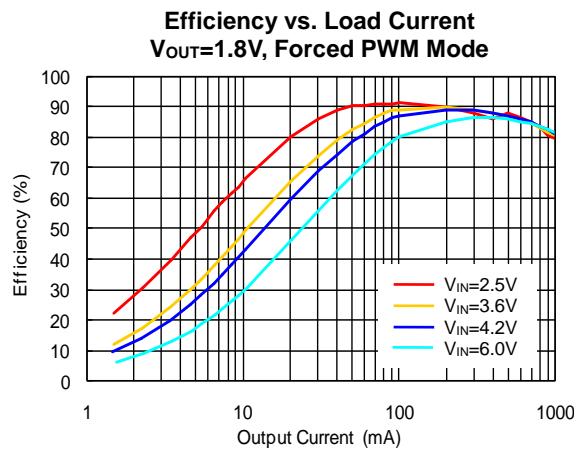
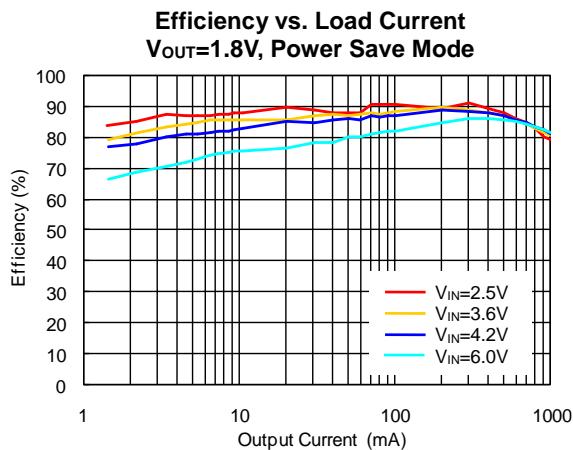
| Symbol | Description | | Value | Unit |
|----------------|--|----------|-------|-------|
| θ_{JA} | Thermal Resistance | SOT23-6 | 190 | °C/W |
| | | DFN6 2x2 | 165 | °C/W |
| P _D | Power Dissipation | SOT23-6 | 0.526 | W |
| | | DFN6 2x2 | 0.606 | W |
| $\Delta P/°C$ | Derating Factor above T _A =25 °C | SOT23-6 | -5.26 | mW/°C |
| | | DFN6 2x2 | -6.06 | mW/°C |

Electrical Characteristics

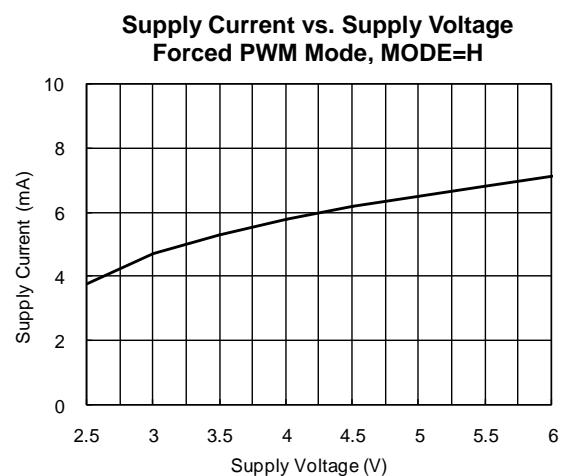
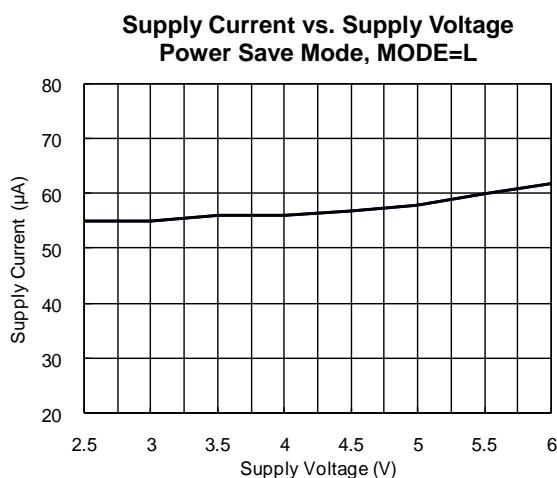
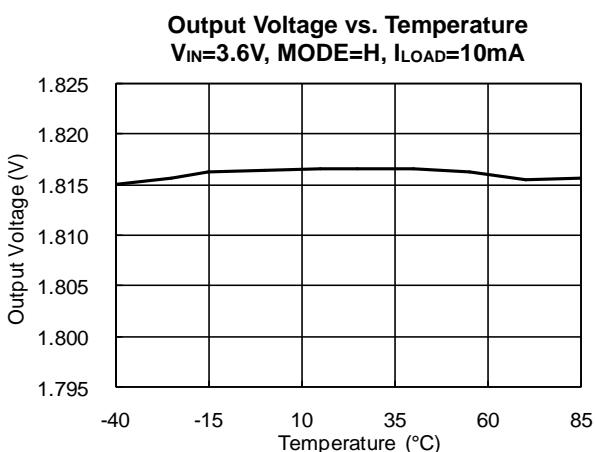
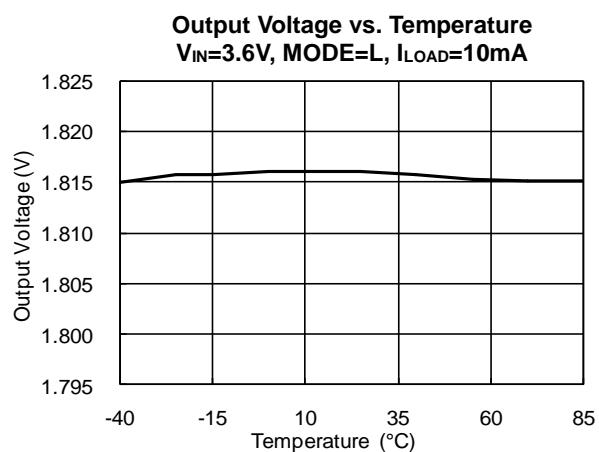
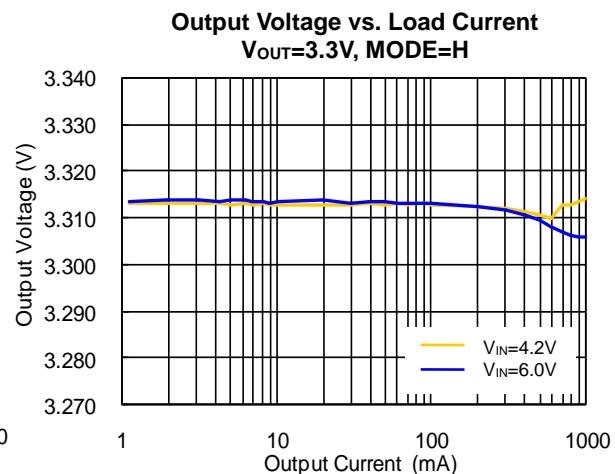
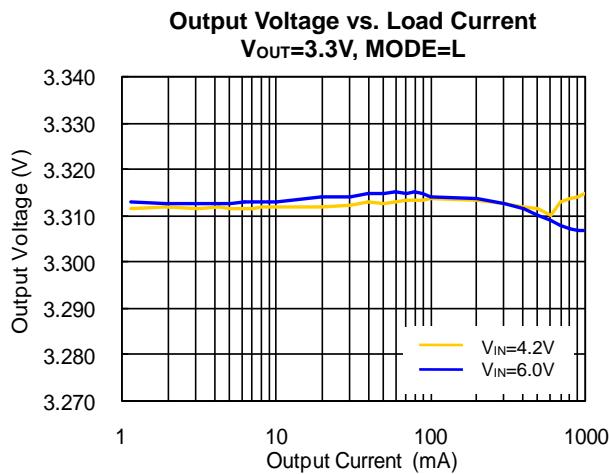
(V_{IN}=V_{EN}=3.6V, T_A=+25 °C, unless otherwise noted)

| Symbol | Parameter | Test Conditions | Min | Typ | Max | Unit |
|---------------------|---|---|-------|-------|-------|------|
| SUPPLY | | | | | | |
| V _{IN} | Input Voltage Range | | 2.5 | | 6.0 | V |
| UVLO | Under Voltage Lockout Threshold | Falling Edge | 1.8 | | 2.3 | V |
| UVLO_HYS | Under Voltage Lockout Hysteresis | | | 200 | | mV |
| I _Q | Input DC Supply Current (MODE=GND) | I _{LOAD} =0mA | | 56 | 80 | µA |
| | Input DC Supply Current (MODE=VIN) | I _{LOAD} =0mA | | 5.6 | | mA |
| I _{SD} | Input Supply Current (Shutdown Mode) | V _{FB} =0V, V _{IN} =6.0V | | 0.1 | 1.0 | µA |
| OUTPUT | | | | | | |
| V _{FB} | Regulated Feedback Voltage | T _A =+25 °C | 0.588 | 0.600 | 0.612 | V |
| I _{FB} | FB Input Bias Current | V _{FB} =0.65V | | | 30 | nA |
| | Output Voltage Line Regulation | 2.5V≤V _{IN} ≤6.0V, I _{OUT} =10mA, MODE=V _{IN} /GND | | 0.10 | 0.20 | %/V |
| | Output Voltage Load Regulation | 0.1A≤I _{OUT} ≤1A | | 0.5 | | %/A |
| I _{O(MAX)} | Maximum Output Current | | 1000 | | | mA |
| t _{SS} | Soft Start Time | | | 400 | | µs |
| I _{SWL} | SW Leakage | V _{EN} =0V, V _{IN} =6V, V _{SW} =0V or 6V | | ±0.01 | ±1 | µA |
| POWER SWITCH | | | | | | |
| R _{DS(ON)} | R _{DS(ON)} of P-CH MOSFET | V _{IN} =3.6V, I _{SW} =100mA | | 0.25 | 0.30 | Ω |
| | R _{DS(ON)} of N-CH MOSFET | V _{IN} =3.6, I _{SW} =-100mA | | 0.18 | 0.23 | Ω |
| I _P | Peak Inductor Current | V _{IN} =2.5V to 6.0V | 1.6 | 1.8 | 2.0 | A |
| | Thermal Shutdown Temperature | | | 150 | | °C |
| | Thermal Shutdown Temperature Hysteresis | | | 20 | | °C |
| OSCILLATOR | | | | | | |
| f | Oscillator Frequency | | 1.95 | 2.25 | 2.55 | MHz |
| ENABLE, MODE | | | | | | |
| V _{IH} | High-Level Threshold | | 1.2 | | | V |
| V _{IL} | Low-Level Threshold | | | | 0.4 | V |
| I _I | Input Leakage Current | | | 0.1 | 1 | µA |

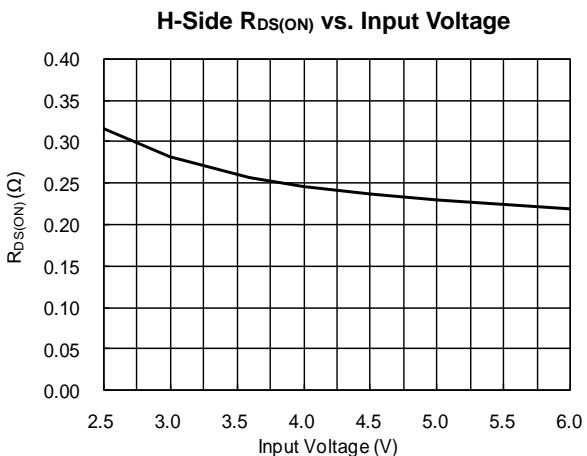
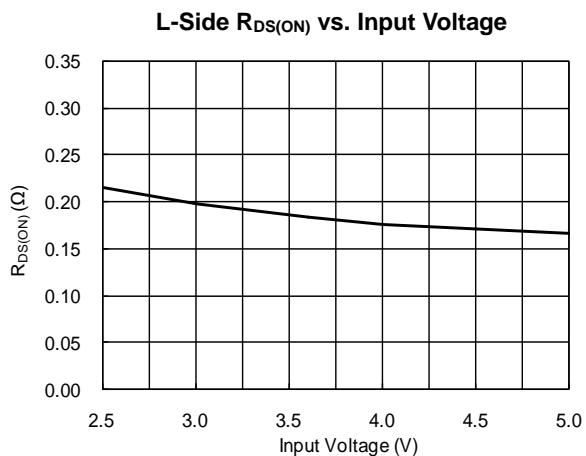
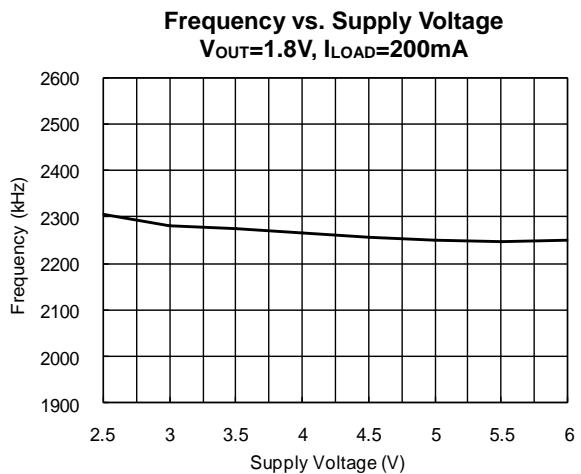
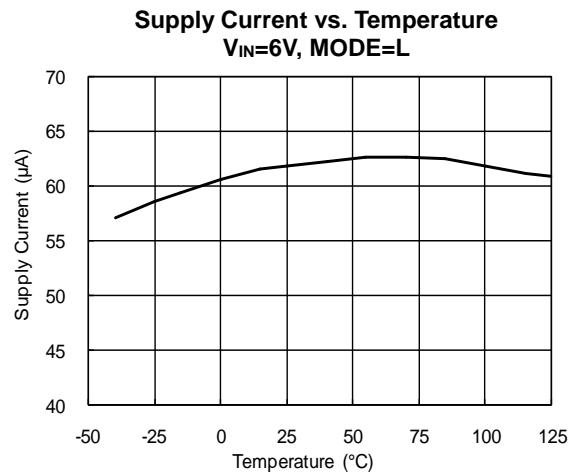
Typical Operating Characteristics



Typical Operating Characteristics (Continued)

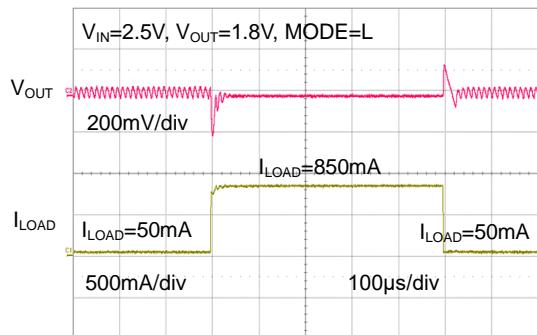


Typical Operating Characteristics (Continued)

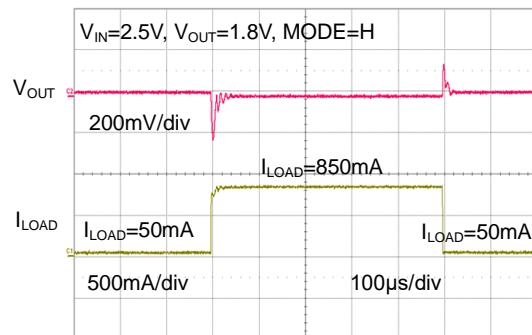


Typical Operating Characteristics (Continued)

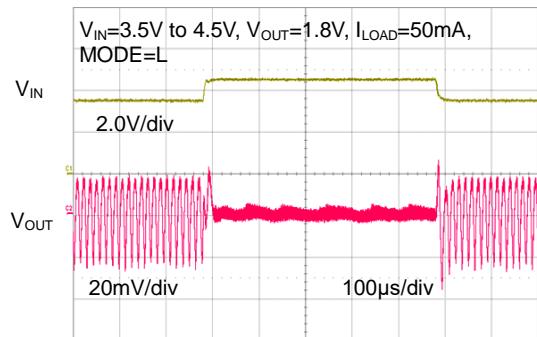
Load Transient Response



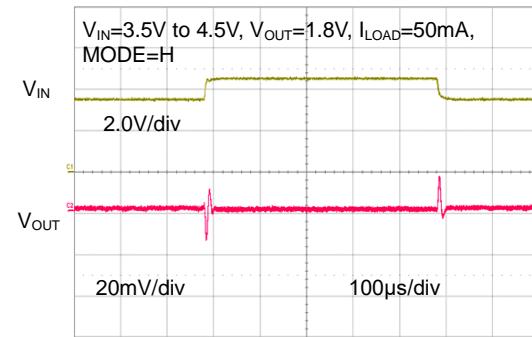
Load Transient Response



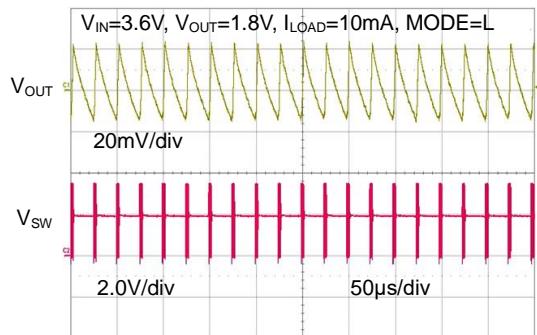
Line Transient Response



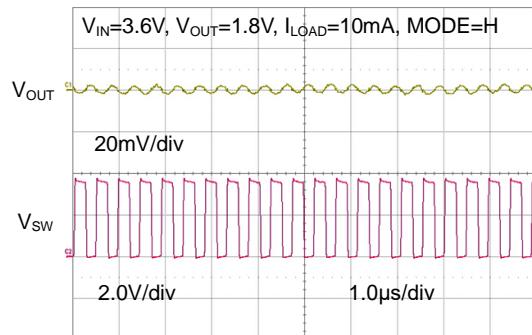
Line Transient Response



PFM Mode Operation



PWM Mode Operation



Application Information

Output Voltage Setting

The output voltage can be calculated according to the formula below with an internal reference voltage V_{REF} typical 0.6V:

$$V_{OUT} = V_{REF} \times \left(1 + \frac{R1}{R2}\right)$$

To minimize the current through the feedback divider network, the recommended value of $R2$ is about $180k\Omega$. The sum of $R1$ and $R2$ should not exceed about $1M\Omega$ to keep the network robust against noise. An external feed forward capacitor $C1$ is required for optimum load transient response. The value of $C1$ should be in the range between $10pF$ and $33pF$.

Route the FB line away from noise sources, such as the inductor or the SW line.

Inductor Selection

A $1\mu H$ to $10\mu H$ inductor with DC current rating at least 25% higher than the maximum load current is recommended for most applications. For best efficiency, the inductor DC resistance shall be $<200m\Omega$.

For most designs, the inductance value can be derived from the following equation:

$$L = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times \Delta I_L \times f_{OSC}}$$

Where ΔI_L is the inductor ripple current. Choose inductor ripple current approximately 30% of the maximum load current, $1000mA$.

The maximum inductor peak current is:

$$I_{L(MAX)} = I_{LOAD} + \frac{\Delta I_L}{2}$$

The following table is a list of recommended inductors.

List of Recommended Inductors

| Dimension [mm ³] | Inductor Type | Supplier |
|------------------------------|---------------|------------------|
| 4.5×4×3.2 | 744773022 | Würth Elektronik |
| 3×3×1.5 | LQH3NPN2R2NM0 | MURATA |
| 3×3×1.5 | LPS3015 | Coilcraft |

Input Capacitor Selection

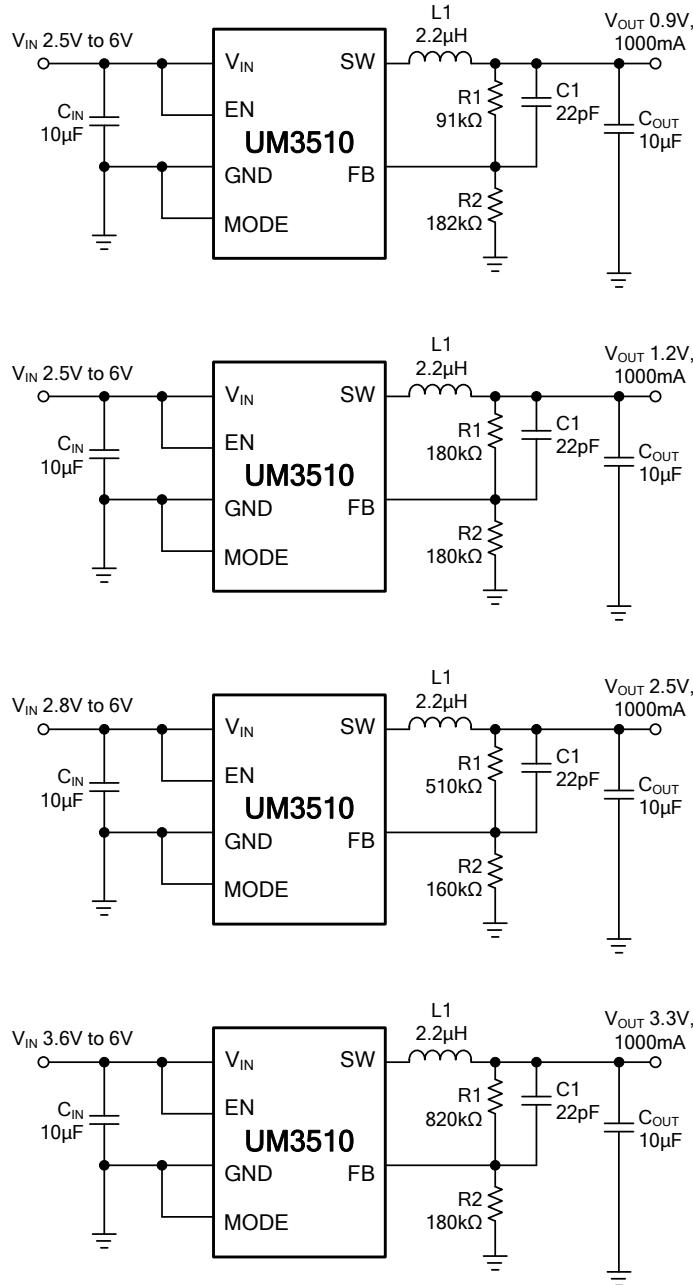
The input capacitor reduces the surge current drawn from the input and switching noise from the device. The input capacitor impedance at the switching frequency shall be less than the input source impedance to prevent high frequency switching current passing to the input. Ceramic capacitors with X5R or X7R dielectrics are highly recommended because of their low ESR and small temperature coefficients. For most applications, a $10\mu F$ capacitor is sufficient. The input capacitor can be increased without any limit for better input voltage filtering.

Output Capacitor Selection

The output capacitor keeps output voltage ripple small and ensures regulation loop stable. The output capacitor impedance shall be low at the switching frequency. Ceramic capacitor with X5R or X7R dielectrics are recommended. The output ripple ΔV_{OUT} is approximately:

$$\Delta V_{OUT} \leq \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times f_{OSC} \times L} \times \left(ESR + \frac{1}{8 \times f_{OSC} \times C_{OUT}}\right)$$

Typical Application Circuit



Layout Guidance

When laying out the PC board, the following suggestions should be taken to ensure proper operation of the UM3510.

1. The power traces, including the GND trace, the SW trace and the VIN trace should be kept short, direct and wide to allow large current flow.
2. Connect the input capacitor C_{IN} to the VIN pin as closely as possible to get good power filter effect.
3. Keep the switching node, SW, away from the sensitive FB node.
4. Do not trace signal line under inductor.

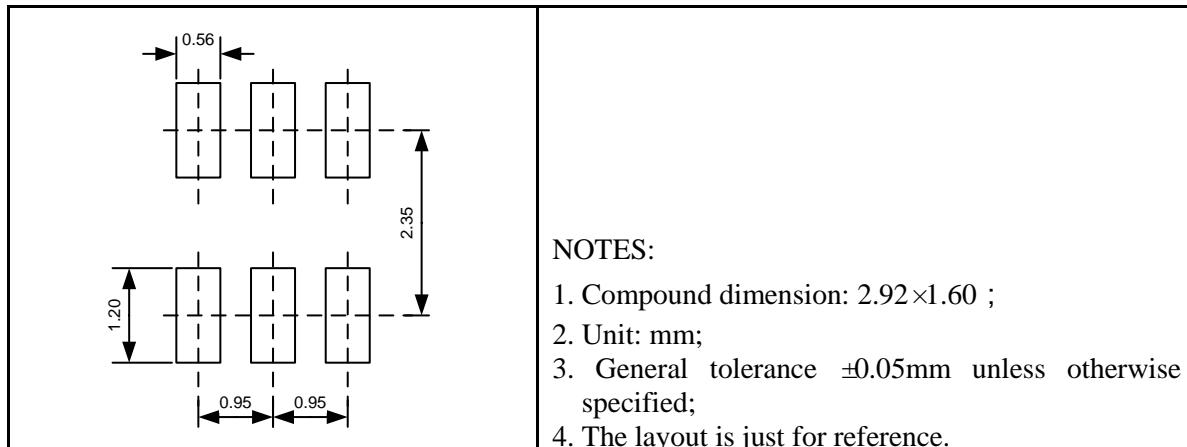
Package Information

UM3510S: SOT23-6

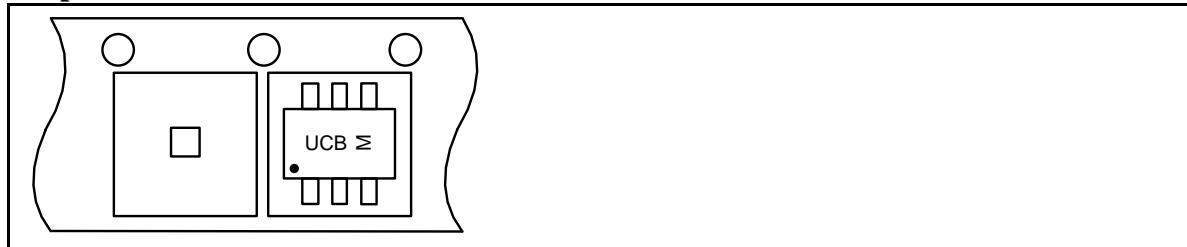
Outline Drawing

| Symbol | DIMENSIONS | | | INCHES | | |
|----------|------------|------|-----------|-----------|-------|-----------|
| | Min | Typ | Max | Min | Typ | Max |
| A | 1.013 | 1.15 | 1.40 | 0.040 | 0.045 | 0.055 |
| A1 | 0.00 | 0.05 | 0.10 | 0.000 | 0.002 | 0.004 |
| A2 | 1.00 | 1.10 | 1.30 | 0.039 | 0.043 | 0.051 |
| b | 0.30 | - | 0.50 | 0.012 | - | 0.020 |
| c | 0.10 | 0.15 | 0.20 | 0.004 | 0.006 | 0.008 |
| D | 2.82 | - | 3.10 | 0.111 | - | 0.122 |
| E | 1.50 | 1.60 | 1.70 | 0.059 | 0.063 | 0.067 |
| E1 | 2.60 | 2.80 | 3.00 | 0.102 | 0.110 | 0.118 |
| e | 0.95REF | | | 0.037REF | | |
| e1 | 1.90REF | | | 0.075REF | | |
| L | 0.30 | - | 0.60 | 0.012 | - | 0.024 |
| θ | 0° | - | 8° | 0° | - | 8° |

Land Pattern



Tape and Reel Orientation

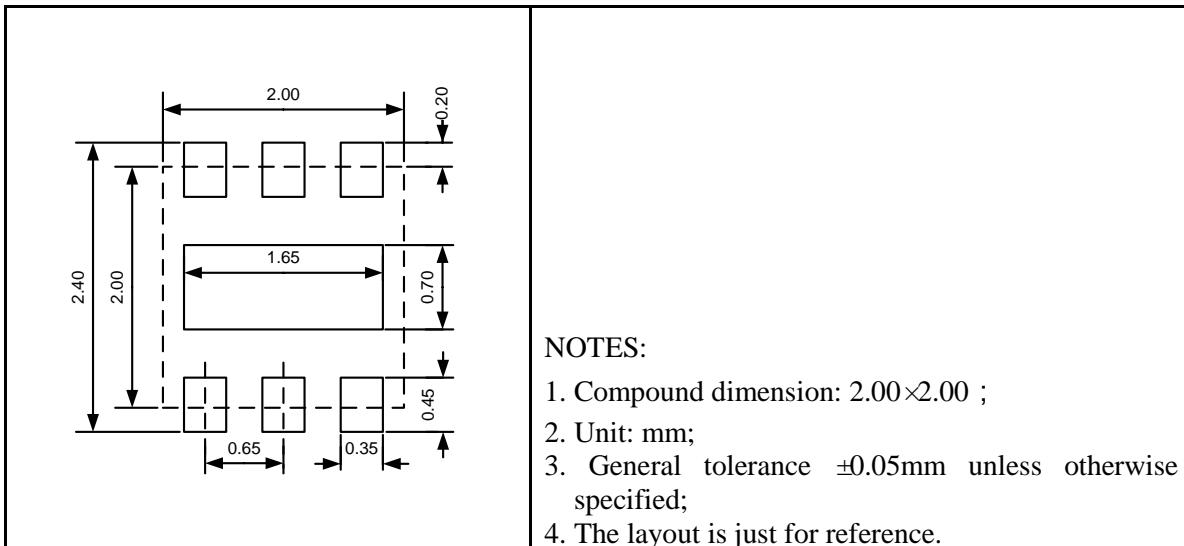


UM3510DA DFN6 2.0×2.0

Outline Drawing

| Symbol | DIMENSIONS | | | INCHES | | |
|--------|------------|------|-------|----------|-------|-------|
| | Min | Typ | Max | Min | Typ | Max |
| A | 0.55 | - | 0.80 | 0.022 | - | 0.031 |
| A1 | 0.00 | - | 0.05 | 0.000 | - | 0.002 |
| A3 | 0.20REF | | | 0.008REF | | |
| b | 0.25 | 0.30 | 0.35 | 0.010 | 0.012 | 0.014 |
| D | 1.924 | 2.00 | 2.076 | 0.076 | 0.079 | 0.082 |
| D2 | 1.35 | - | 1.75 | 0.053 | - | 0.069 |
| E | 1.924 | 2.00 | 2.076 | 0.076 | 0.079 | 0.082 |
| E2 | 0.65 | - | 1.06 | 0.026 | - | 0.042 |
| e | 0.65BSC | | | 0.026BSC | | |
| L | 0.224 | - | 0.45 | 0.009 | - | 0.018 |

Land Pattern



Tape and Reel Orientation



GREEN COMPLIANCE

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